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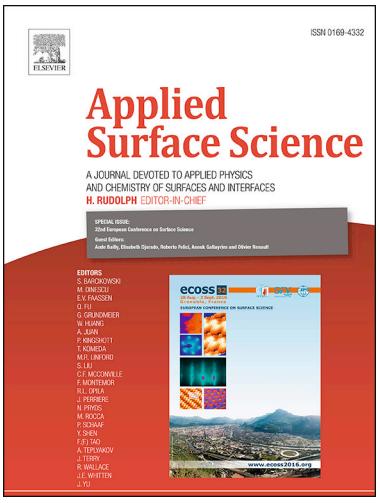

Full Length Article

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Thiol-functionalization of Mn_5Ge_3 thin films

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HIGHLIGHTS

The surface state of Mn_5Ge_3 exposed to air and common colvents, is analyzed by XPS.

The surface free energy of Mn_5Ge_3 is calculated with the OWRK method.

The grafting of Mn_5Ge_3 films by octane- and perfluorodecane-thiol SAMs is proposed.

KEYWORDS

thiol; passivation; self-assembled monolayers; manganese germanide; Mn_5Ge_3; wettability; spintronics; surface free energy.

ABSTRACT

Hybrid organic/inorganic interfaces could pave the way to chemically designed or new multifunctional electronic devices, in particular in the spintronics field where, for instance, the interfacial spin

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